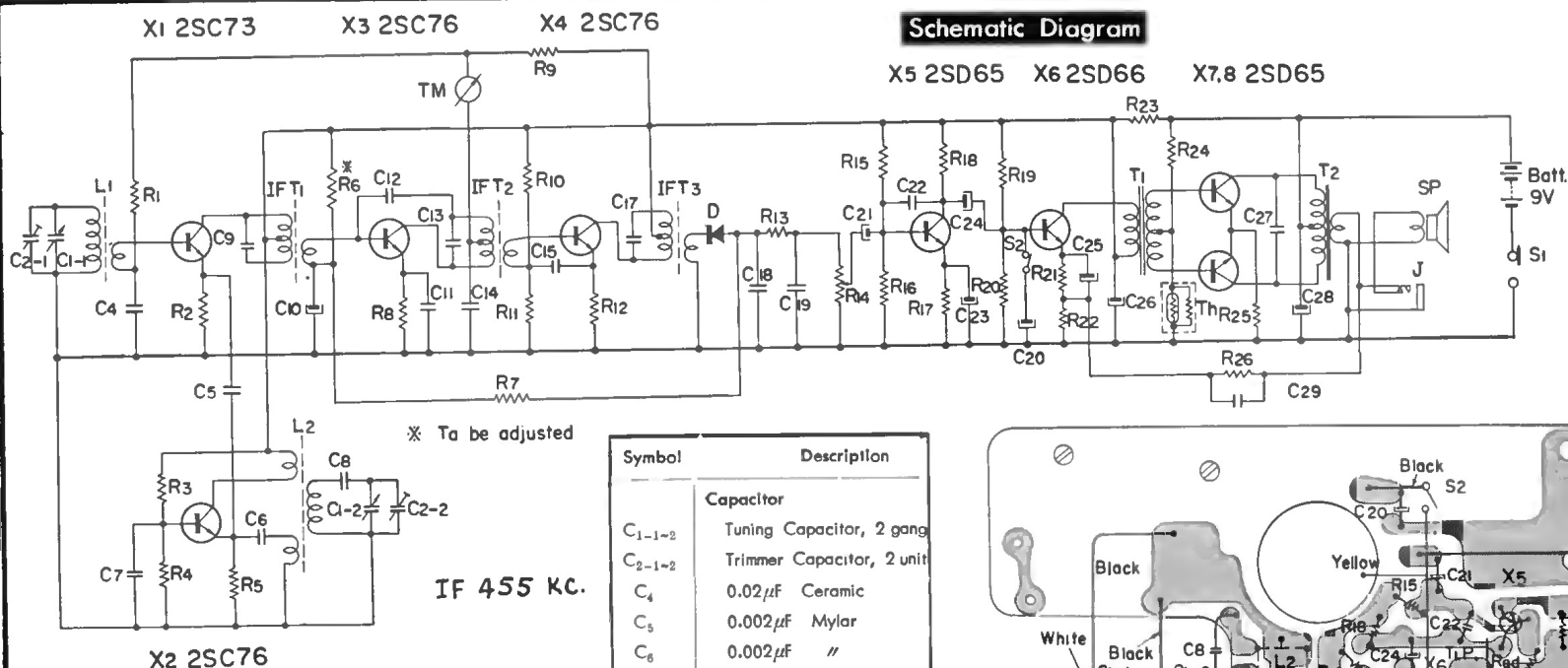


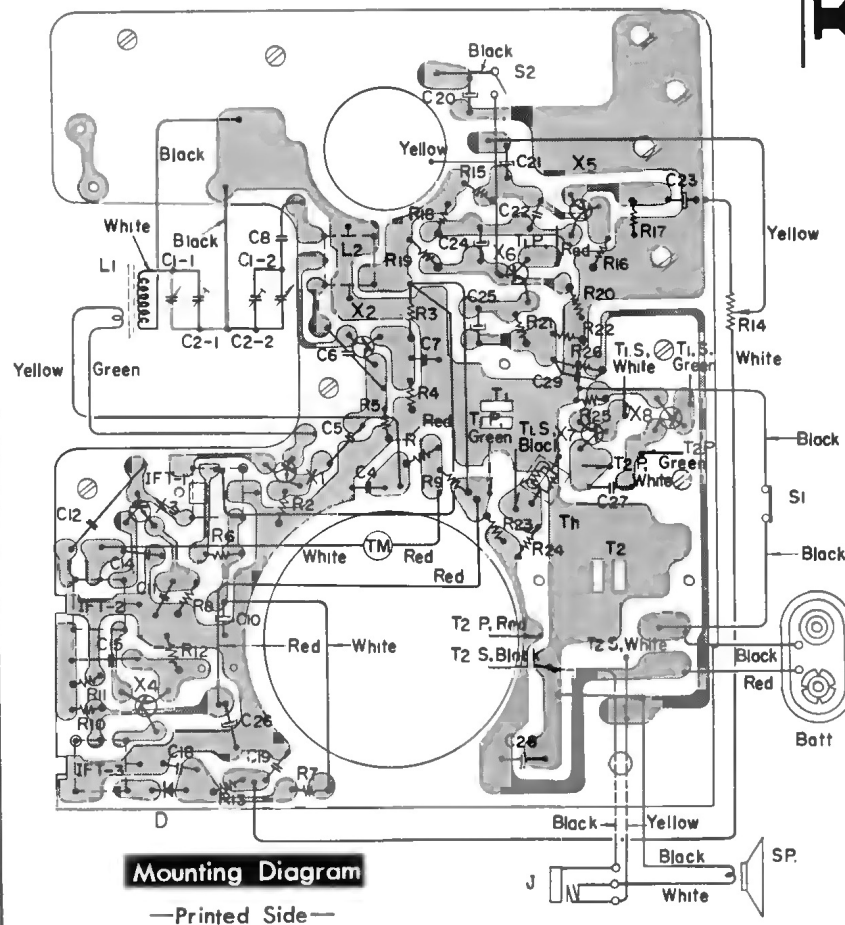
SONY

TR-830



Symbol	Description	Symbol	Description
X ₁	Transistor 2SC73	R ₈	470 Ω 1/16W Carbon
X ₂	" 2SC76	R ₉	10K Ω " "
X ₃	" 2SC76	R ₁₀	39K Ω " "
X ₄	" 2SC76	R ₁₁	3.3K Ω " "
X ₅	" 2SD65	R ₁₂	470 Ω " "
X ₆	" 2SD66	R ₁₃	1.8K Ω " "
X ₇	" 2SD65	R ₁₄	5K Ω Volume Control
X ₈	" 2SD65	R ₁₅	36K Ω 1/16W Carbon
D	Diode 1T23G	R ₁₆	5.6K Ω " "
Th	Thermistor CS-120	R ₁₇	1K Ω " "
Resistor		R ₁₈	1K Ω " "
R ₁	10K Ω 1/16W Carbon	R ₁₉	27K Ω " "
R ₂	30K Ω " "	R ₂₀	10K Ω " "
R ₃	39K Ω " "	R ₂₁	1K Ω " "
R ₄	5.6K Ω " "	R ₂₂	10 Ω " "
R ₅	2.2K Ω " "	R ₂₃	220 Ω " "
*R ₆	120K Ω " "	R ₂₄	7.5K Ω " "
R ₇	5.6K Ω " "	R ₂₅	10 Ω " "
		R ₂₆	680 Ω " "

Symbol	Description
Capacitor	
C ₁₋₁₋₂	Tuning Capacitor, 2 gang
C ₂₋₁₋₂	Trimmer Capacitor, 2 unit
C ₄	0.02 μF Ceramic
C ₅	0.002 μF Mylar
C ₆	0.002 μF "
C ₇	0.01 μF Ceramic
C ₈	130PF Styrol
C ₉	150PF (built in IFT ₁)
C ₁₀	10 μF 3V Electrolytic
C ₁₁	0.02 μF Ceramic
C ₁₂	1PF "
C ₁₃	150PF (built in IFT ₂)
C ₁₄	0.01 μF Ceramic
C ₁₅	0.01 μF "
C ₁₇	150PF (built in IFT ₃)
C ₁₈	0.02 μF Ceramic
C ₁₉	0.01 μF "
C ₂₀	0.3 μF 15V Electrolytic
C ₂₁	10 μF 3V "
C ₂₂	0.005 μF Mylar
C ₂₃	10 μF 3V Electrolytic
C ₂₄	10 μF 6V "
C ₂₅	30 μF 3V "
C ₂₆	30 μF 10V "
C ₂₇	0.04 μF Ceramic
C ₂₈	50 μF 10V Electrolytic
C ₂₉	0.02 μF Ceramic



* To be adjusted

C29 is mounted on the printed side

Model TR-830



* To be adjusted

